



ADC-912

CMOS MICROPROCESSOR-COMPATIBLE
12-BIT A/D CONVERTER

Precision Monolithics Inc.

FEATURES

- Low Cost
- Low Transition Noise Between Codes
- 12-Bit Accurate
 - ±1/2 LSB Nonlinearity Error Over Temperature
 - No Missing Codes at All Temperatures
- 12 Microsecond Conversion Time
- Internal or External Clock
- Fast 90ns Bus Access and Disconnect Time
- 8 or 16-Bit Data Bus Compatible
- Improved ESD Resistant Design
- Low 95mW Power Consumption
- Space Saving 24-Pin 0.3" DIP, or 24-Lead SOL
- Available in Die Form

APPLICATIONS

- Data Acquisition Systems
- DSP System Front End
- Process Control Systems
- Portable Instrumentation

ORDERING INFORMATION†

INL (LSB)	MILITARY*†† TEMPERATURE -55°C TO +125°C	EXTENDED INDUSTRIAL†† TEMPERATURE -40°C TO +85°C	COMMERCIAL TEMPERATURE 0°C TO +70°C
±1/2	ADC912BW	ADC912EP	—
±1	—	ADC912FW	—
±1	—	ADC912FP	ADC912HP
±1	—	ADC912FS	ADC912HS††

* For devices processed in total compliance to MIL-STD-883, add /883 after part number. Consult factory for 883 data sheet.

† Burn-in is available on commercial and industrial temperature range parts in CerDIP, plastic DIP, and TO-can packages. For ordering information, see PMI's Data Book, Section 2.

†† For availability and burn-in information, contact your local sales office.

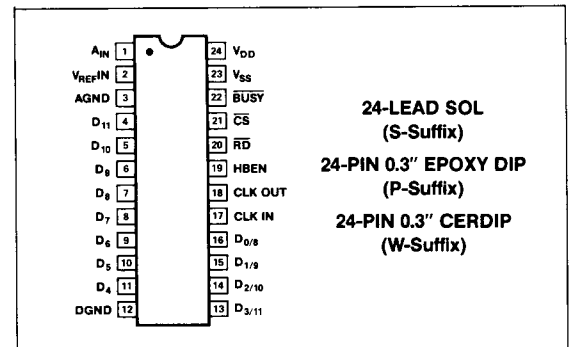
GENERAL DESCRIPTION

The ADC-912 is a monolithic 12-bit accurate CMOS A/D converter. It contains a complete successive approximation A/D converter built with a high accuracy D/A converter, a precision bipolar transistor high-speed comparator, and successive approximation logic including three-state bus interface for logic compatibility. The accuracy of the ADC-912 results from the addition of precision bipolar transistors to PMI's advanced-oxide isolated silicon-gate CMOS process. Particular attention was paid to the reduction of transition noise between adjacent codes achieving a 1/6 LSB uncertainty. The low noise design produces the same digital output for DC analog inputs not located at a transition voltage, see the Code Repetition and Transition Noise plots below. NPN transistors also provide excellent bus interface timing, 90ns access and bus disconnect time which results in faster data transfer without the need for wait states. An external 1MHz clock provides a 12μs conversion time.

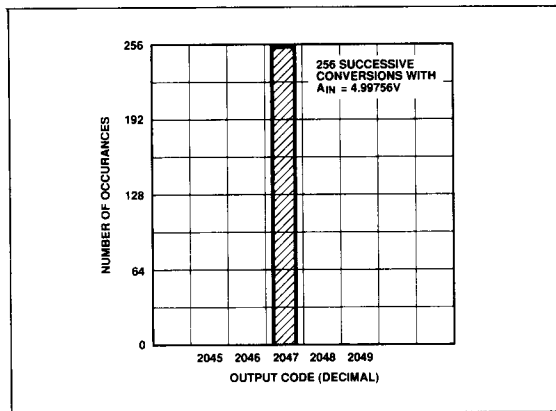
In stand-alone applications an internal clock can be used with an external crystal.

An external negative five-volt reference sets the 0 to +10 volt input range. Plus five and minus 12 volt power supplies result in 95mW of total power consumption.

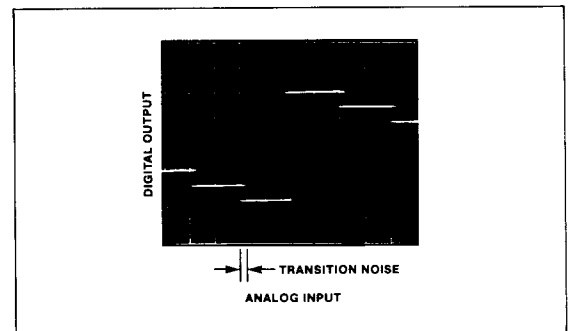
PIN CONNECTIONS



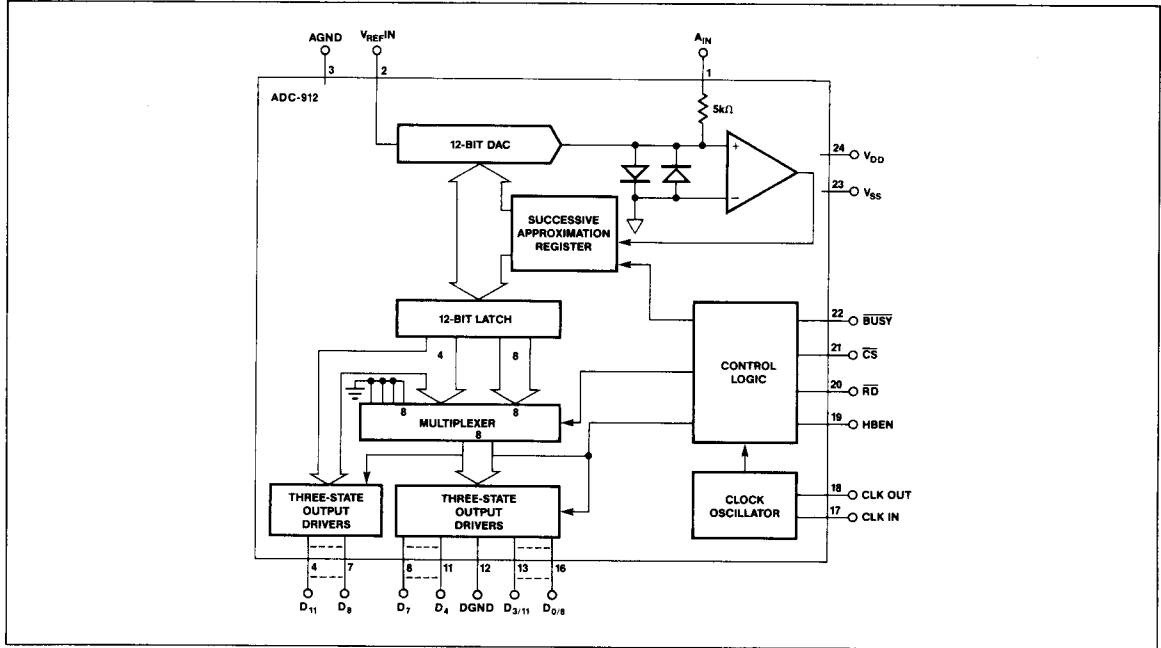
CODE REPETITION



TRANSITION NOISE CROSS PLOT



FUNCTIONAL DIAGRAM



ABSOLUTE MAXIMUM RATINGS ($T_A = +25^\circ\text{C}$, unless otherwise noted)

V_{DD} to DGND -0.3V to $+7\text{V}$
 V_{SS} to DGND $+0.3\text{V}$ to -17V
 $V_{REF IN}$ to AGND V_{SS}, V_{DD}
AGND to DGND $-0.3\text{V}, V_{DD} + 0.3\text{V}$
 A_{IN} to AGND -15V to $+15\text{V}$
Digital Input Voltage to DGND
Pins 17, 19-21 $-0.3\text{V}, V_{DD} + 0.3\text{V}$
Digital Output Voltage to DGND
Pins 4-11, 13-16, 18, 22 $-0.3\text{V}, V_{DD} + 0.3\text{V}$
Operating Temperature Range
HP, HS 0°C to $+70^\circ\text{C}$
EP, FP, FW, FS -40°C to $+85^\circ\text{C}$
BW, BTC -55°C to $+125^\circ\text{C}$
Junction Temperature $+150^\circ\text{C}$

Storage Temperature -65°C to $+150^\circ\text{C}$
Lead Temperature (Soldering, 60 sec) 300°C

PACKAGE TYPE	θ_{JA} (Note 1)	θ_{JC}	UNITS
20-Pin Hermetic DIP (Z)	76	11	$^\circ\text{C}/\text{W}$
20-Pin Plastic DIP (P)	69	27	$^\circ\text{C}/\text{W}$
20-Pin SOL (S)	88	25	$^\circ\text{C}/\text{W}$

NOTE:

1. θ_{JA} is specified for worst case mounting conditions, i.e., θ_{JA} is specified for device in socket for CerDIP and P-DIP packages; θ_{JA} is specified for device soldered to printed circuit board for SOL package.

CAUTION:

Stress above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other condition above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS at $V_{DD} = +5\text{V}$, $V_{SS} = -12$ or -15V , $V_{REF} = -5\text{V}$, Analog Input 0 to $+10\text{V}$; $f_{CLK} = 1\text{MHz}$; $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$ for ADC-912E/F, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ for ADC-912H, $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$ for ADC-912B, unless otherwise noted. Specifications apply to Slow-Memory Mode. (Note 7)

PARAMETER	SYMBOL	CONDITIONS	ADC-912			UNITS
			MIN	TYP	MAX	
Integral Nonlinearity	INL	B/E Grades F/H Grades	-1/2	—	+1/2	LSB
			-1	—	+1	
Differential Nonlinearity	DNL		-1	—	+1	LSB
Offset Error	V_{ZSE}		-5	—	+5	LSB
Gain Error	G_{FSE}		-8	—	+8	LSB



ELECTRICAL CHARACTERISTICS at $V_{DD} = +5V$, $V_{SS} = -12$ or $-15V$, $V_{REF} = -5V$, Analog Input 0 to $+10V$; $f_{CLK} = 1MHz$; $-40^{\circ}C \leq T_A \leq +85^{\circ}C$ for ADC-912E/F, $0^{\circ}C \leq T_A \leq +70^{\circ}C$ for ADC-912H, $-55^{\circ}C \leq T_A \leq +125^{\circ}C$ for ADC-912B, unless otherwise noted. Specifications apply to Slow-Memory Mode. *Continued*

PARAMETER	SYMBOL	CONDITIONS	ADC-912			UNITS
			MIN	TYP	MAX	
Full-Scale Tempco (Note 1)	TCG _{FS}		—	5	+15	ppm/°C
Input Voltage Range	V _{IN}		0	—	+10	V
Input Current Range	I _{IN}		0	—	+3	mA
Power Supply Rejection Ratio	PSRR+	$\Delta V_{DD} = \pm 5\%$	—	1/2	4	LSB
	PSRR-	$\Delta V_{SS} = \pm 5\%$	—	1/8	4	
Logic Input High Voltage	V _{INH}	\overline{CS} , \overline{RD} , HBEN	2.4	—	—	V
Logic Input Low Voltage	V _{INL}	\overline{CS} , \overline{RD} , HBEN	—	—	0.8	V
Logic Input Current	I _{IN}	\overline{CS} , \overline{RD} , HBEN	—	—	± 1	μA
Digital Input Capacitance	C _{IN}	Digital Input, \overline{CS} , \overline{RD} , HBEN, CLK IN (Note 1)	—	7	10	pF
Logic Output High Voltage	V _{OH}	I _{SOURCE} = 0.2mA	4	—	—	V
Logic Output Low Voltage	V _{OL}	I _{SINK} = 1.6mA	—	—	0.4	V
Three-State Output Leakage	I _{OZ}	D11-D0/8	—	—	10	μA
Digital Output Capacitance	C _{OUT}	D11-D0/8 (Note 1)	—	8	15	pF
Positive Supply Current	I _{DD}	V _{DD} = +5V (Note 2)	—	5	7	mA
Negative Supply Current	I _{SS}	V _{SS} = -12V (Note 2)	—	3	5	mA
Power Consumption	P _{diss}	V _{DD} = +5V, V _{SS} = -12V (Note 2)	—	70	95	mW
Conversion Time	T _c	f _{CLK} = 1MHz (Note 6) Synchronous Clock	—	—	12.5	μs
		Asynchronous Clock	12	—	13.5	

TIMING CHARACTERISTICS (Notes 1, 3)

See Figures 3 to 6

CS to RD Set-up Time	t ₁		20	—	—	ns	
RD to BUSY Propagation Delay	t ₂		—	—	150	ns	
Data Access Time After RD	t ₃	(Note 4)	C _L = 20pF	—	50	90	ns
			C _L = 100pF	—	65	125	
Read Pulse Width	t ₄	(Note 4)	90	—	—	ns	
CS to RD Hold Time	t ₅		0	—	—	ns	
New Data Valid After BUSY	t ₆	C _L = 100pF (Note 4)	—	-30	0	ns	
Bus Disconnect Time	t ₇	(Note 5)	20	50	90	ns	
HBEN to RD Set-up Time	t ₈		20	—	—	ns	
HBEN to RD Hold Time	t ₉		0	—	—	ns	
Delay Between Successive Read Operations	t ₁₀		250	200	—	ns	

NOTES:

- Guaranteed by design.
- Converter inactive; \overline{CS} , \overline{RD} = HIGH, A_{IN} = +10V.
- All input control signals are specified with $t_r = t_f = 5ns$ (10% to 90% of +5V) and timed from a voltage level of 1.6V.
- t₃, t₄ and t₆ are measured with the load circuits of Figure 1 and timed for an output to cross 0.8V or 2.4V.
- t₇ is the time required for the data lines to change 0.5V when loaded with the circuits of Figure 2.
- See Synchronizing Start Conversion information in Converter Operation Details.
- Typicals (TYP) are median values measured at 25°C. See Typical Performance Characteristics for additional information.

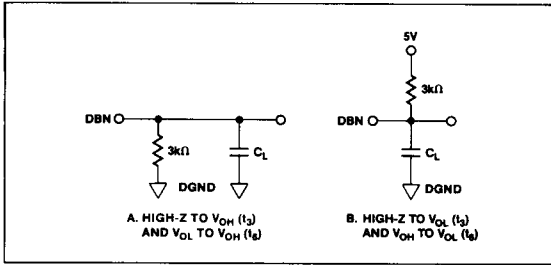


FIGURE 1: Load Circuits for Access Time

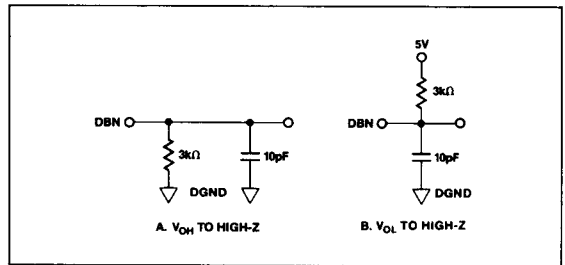


FIGURE 2: Load Circuits for Output Float Delay

TABLE 1: Pin Function Description

PIN	MNEMONIC	DESCRIPTION
1	A _{IN}	Analog Input. 0 to +10 volts.
2	V _{REFIN}	Voltage Reference Input. Requires external -5 volt reference.
3	AGND	Analog Ground
4...11	D ₁₁ ...D ₄	Three State data outputs become active when \overline{CS} and \overline{RD} are brought low.
13...16	D _{3/11} ...D _{0/8}	Individual pin function is dependent upon High Byte Enable (HBEN) input. DATA BUS OUTPUT, \overline{CS} & \overline{RD} = LOW

	Pin 4	Pin 5	Pin 6	Pin 7	Pin 8	Pin 9	Pin 10	Pin 11	Pin 13	Pin 14	Pin 15	Pin 16
MNEMONIC*	D ₁₁	D ₁₀	D ₉	D ₈	D ₇	D ₆	D ₅	D ₄	D _{3/11}	D _{2/10}	D _{1/9}	D _{0/8}
HBEN = LOW	DB ₁₁	DB ₁₀	DB ₉	DB ₈	DB ₇	DB ₆	DB ₅	DB ₄	DB ₃	DB ₂	DB ₁	DB ₀
HBEN = HIGH	DB ₁₁	DB ₁₀	DB ₉	DB ₈	LOW	LOW	LOW	LOW	DB ₁₁	DB ₁₀	DB ₉	DB ₈

NOTES:

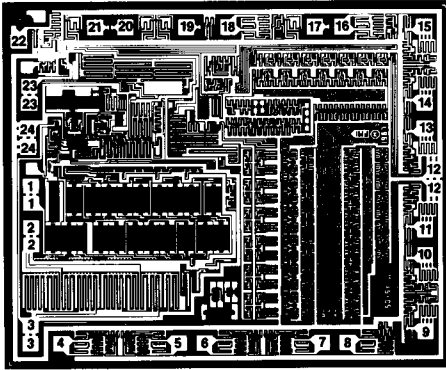
*D₁₁...D_{0/8} are the ADC data output pins.
DB₁₁...DB₀ are the 12-bit conversion results, DB₁₁ is the MSB.

12	DGND	Digital Ground
17	CLK IN	Clock Input pin. An external TTL compatible clock may be applied to this pin. Alternatively a crystal or ceramic resonator may be connected between CLK IN (Pin 17) and CLK OUT (Pin 18).
18	CLK OUT	Clock Output pin. An inverted CLK IN signal appears at CLK OUT when an external clock is used. See CLK IN (Pin 17) description for crystal (resonator).
19	HBEN	High Byte Enable input. Its primary function is to multiplex the 12 bits of conversion data onto the lower D ₇ ...D _{0/8} outputs (4 MSBs or 8 LSBs). See Pin description 4...11 and 13...16. Also disables conversion start when HBEN is high.
20	\overline{RD}	READ input. This active LOW signal, in conjunction with \overline{CS} is used to enable the output data three-state drivers and initiates a conversion if \overline{CS} and HBEN are low.
21	\overline{CS}	CHIP SELECT input. This active LOW signal, in conjunction with \overline{RD} is used to enable the output data three-state drivers and initiates a conversion if \overline{RD} and HBEN are low.
22	\overline{BUSY}	\overline{BUSY} output indicates converter status. \overline{BUSY} is LOW during conversion.
23	V _{SS}	Negative Supply, -12V or -15V.
24	V _{DD}	Positive Supply, +5V.

TABLE 2: Analog Input to Digital Output Code Conversion

	ANALOG INPUT VOLTAGE		OUTPUT CODE*	
	0 TO +10V	-10V TO +10V	DB ₁₁ (MSB)	DB ₀ (LSB)
+FS - 1LSB	9.9976V	9.9951V	1111	1111 1111
+FS - 1½LSB	9.9964	9.9927	1111	1111 1111 φ
Mid Scale + ½LSB	5.0012	0.0024	1000	0000 0000 φ
Mid Scale	5.0000	0.0000	1000	0000 0000
-FS + ½LSB	0.0012	-9.9976	0000	0000 0000 φ
-FS	0.0000	-10.0000	0000	0000 0000

*The symbol "φ" indicates a 0 or 1 with equal probability.

DICE CHARACTERISTICS


DIE SIZE 0.122 × 0.148 inch, 18,056 sq. mils
(3.098 × 3.759 mm, 11.65 sq. mm)

- | | |
|----------------|--------------------------|
| 1. A_{IN} | 13. $D_{3/11}$ |
| 2. V_{REFIN} | 14. $D_{2/10}$ |
| 3. AGND | 15. $D_{1/9}$ |
| 4. D_{11} | 16. $D_{0/8}$ |
| 5. D_{10} | 17. CLK IN |
| 6. D_9 | 18. CLK OUT |
| 7. D_8 | 19. HBEN |
| 8. D_7 | 20. RD |
| 9. D_6 | 21. CS |
| 10. D_5 | 22. BUSY |
| 11. D_4 | 23. V_{SS} |
| 12. DGND | 24. V_{DD} (Substrate) |

For additional DICE ordering information, refer to PMI's Data Book, Section 2.

WAFER TEST LIMITS at $V_{DD} = +5V$, $V_{SS} = -12V$ or $-15V$, $V_{REF} = -5V$, $A_{IN} = 0V$ to $+10V$, and $T_A = +25^\circ C$, unless otherwise noted.

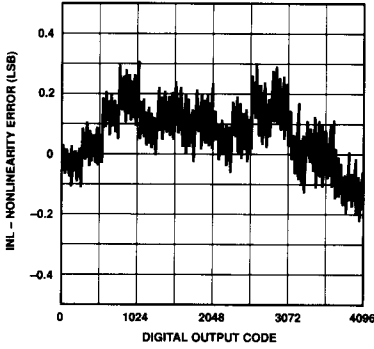
PARAMETER	SYMBOL	CONDITIONS	ADC-912G	
			LIMIT	UNITS
Integral Nonlinearity	INL		±1	LSB MAX
Differential Nonlinearity	DNL		±1	LSB MAX
Offset Error	V_{ZSE}	Guaranteed by Design	±8	LSB MAX
Gain Error	G_{FSE}		±8	LSB MAX
Analog Input Resistance	R_{AIN}		4/6	KΩ MIN/MAX
Logic Input High Voltage	V_{INH}	CS, RD, HBEN	2.4	V MIN
Logic Input Low Voltage	V_{INL}	CS, RD, HBEN	0.8	V MAX
Logic Input Current	I_{IN}	CS, RD, HBEN	±1	μA MAX
Logic Output High Voltage	V_{OH}	$I_{SOURCE} = 0.2mA$	4	V MIN
Logic Output Low Voltage	V_{OL}	$I_{SINK} = 1.6mA$	0.4	V MAX
Positive Supply Current	I_{DD}	$V_{DD} = +5V$, CS = RD = V_{DD} , $A_{IN} = +10V$	7	mA MAX
Negative Supply Current	I_{SS}	$V_{SS} = -12V$, CS = RD = V_{DD} , $A_{IN} = +10V$	5	mA MAX

NOTE:

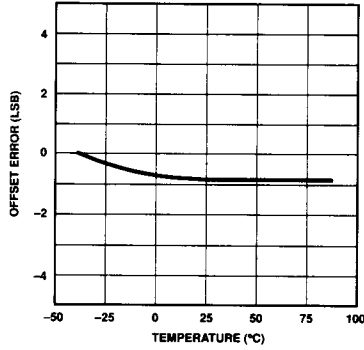
Electrical tests are performed at wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed for standard product dice. Consult factory to negotiate specifications based on dice lot qualification through sample lot assembly and testing.

TYPICAL PERFORMANCE CHARACTERISTICS

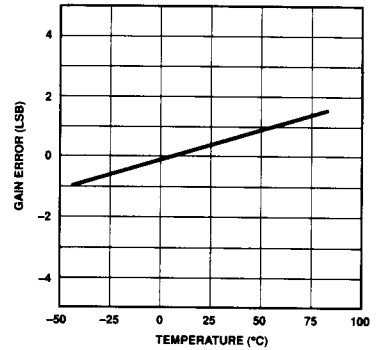
NONLINEARITY ERROR vs DIGITAL OUTPUT CODE



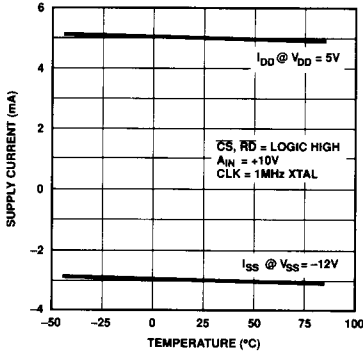
OFFSET ERROR vs TEMPERATURE



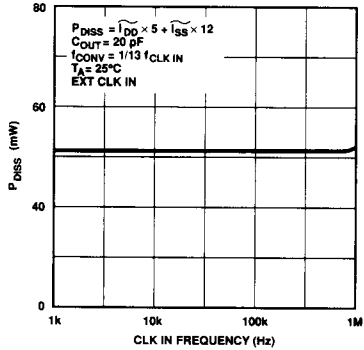
GAIN ERROR vs TEMPERATURE



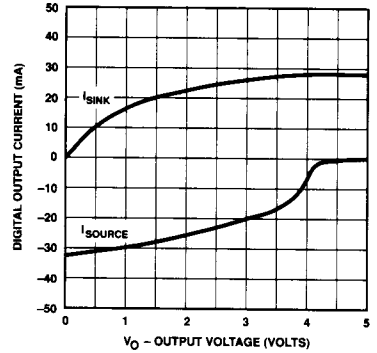
SUPPLY CURRENT vs TEMPERATURE



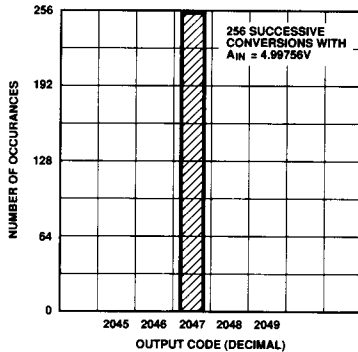
POWER DISSIPATION vs CLK IN FREQUENCY



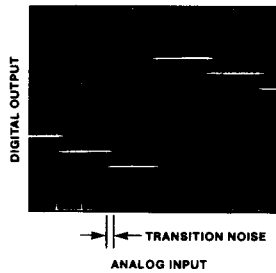
DIGITAL OUTPUT CURRENT vs OUTPUT VOLTAGE



CODE REPETITION



TRANSITION NOISE CROSS PLOT



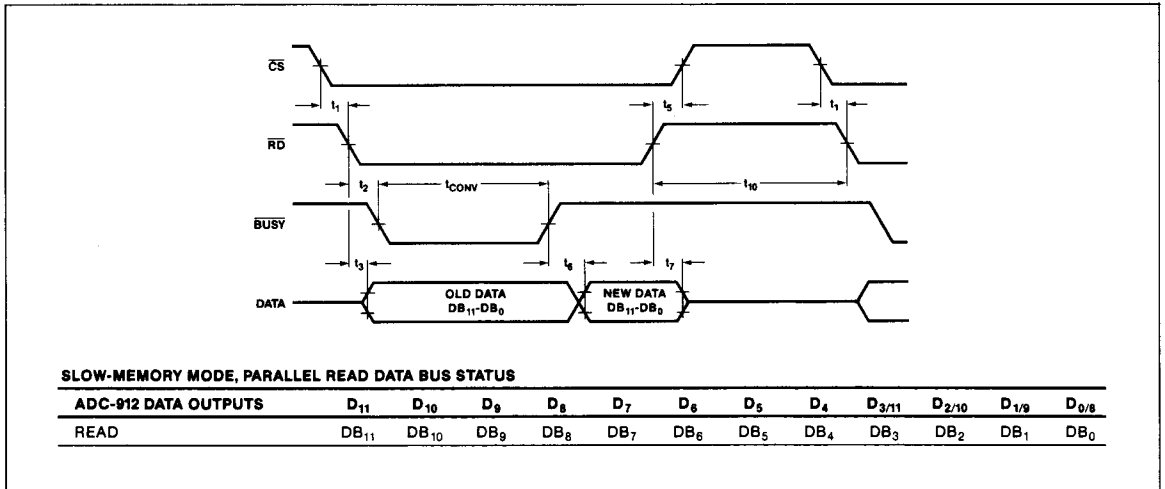


FIGURE 3: Parallel Read Timing Diagram, Slow-Memory Mode (HBEN = LOW)

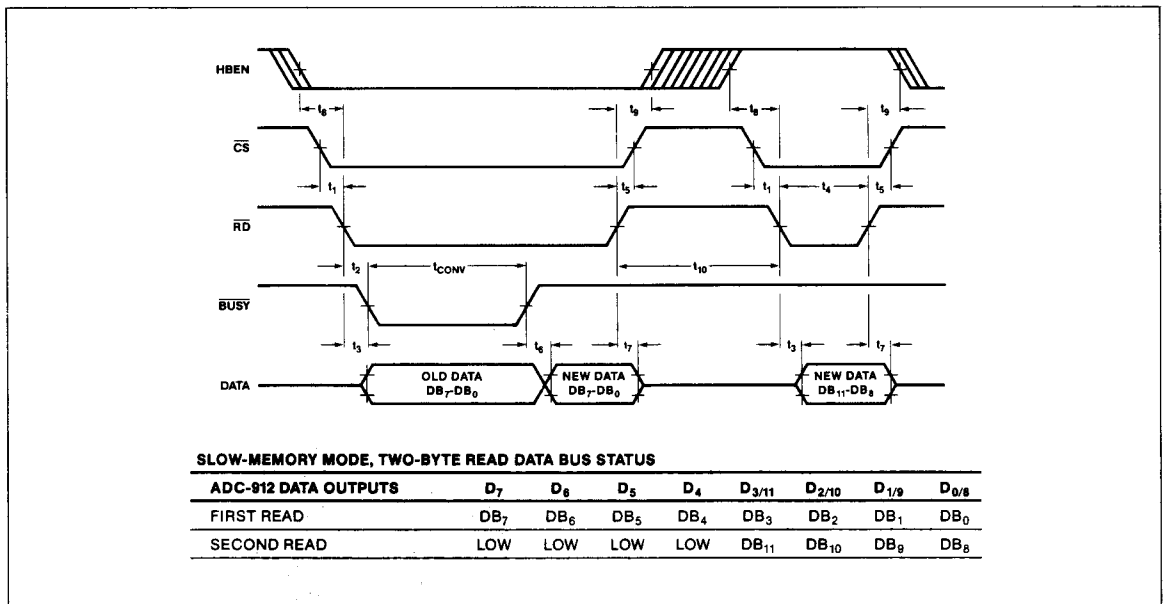
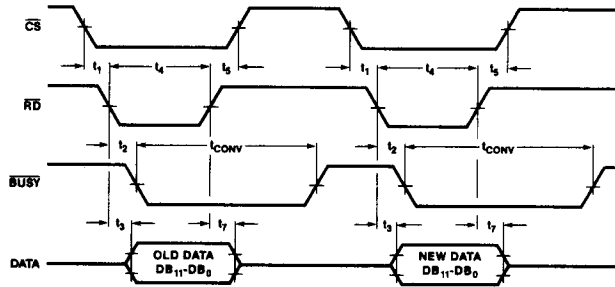


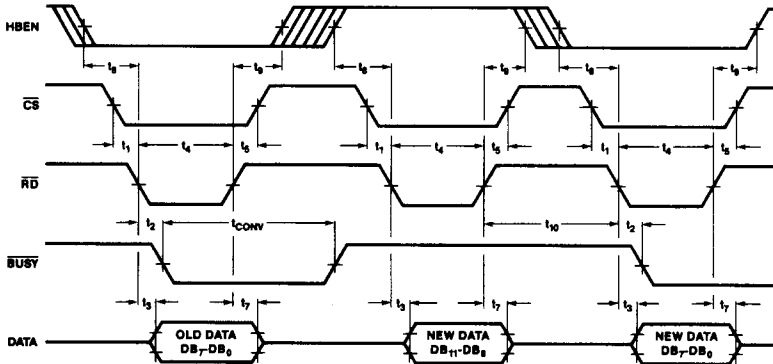
FIGURE 4: Two-Byte Read Timing Diagram, Slow-Memory Mode



ROM MODE, PARALLEL READ DATA BUS STATUS

ADC-912 DATA OUTPUTS	D ₁₁	D ₁₀	D ₉	D ₈	D ₇	D ₆	D ₅	D ₄	D _{3/11}	D _{2/10}	D _{1/9}	D _{0/8}
FIRST READ (OLD DATA)	DB ₁₁	DB ₁₀	DB ₉	DB ₈	DB ₇	DB ₆	DB ₅	DB ₄	DB ₃	DB ₂	DB ₁	DB ₀
SECOND READ	DB ₁₁	DB ₁₀	DB ₉	DB ₈	DB ₇	DB ₆	DB ₅	DB ₄	DB ₃	DB ₂	DB ₁	DB ₀

FIGURE 5: Parallel Read Timing Diagram, ROM Mode (HBEN = LOW)



ROM MODE, TWO-BYTE READ DATA BUS STATUS

ADC-912 DATA OUTPUTS	D ₇	D ₆	D ₅	D ₄	D _{3/11}	D _{2/10}	D _{1/9}	D _{0/8}
FIRST READ (OLD DATA)	DB ₇	DB ₆	DB ₅	DB ₄	DB ₃	DB ₂	DB ₁	DB ₀
SECOND READ	LOW	LOW	LOW	LOW	DB ₁₁	DB ₁₀	DB ₉	DB ₈
THIRD READ	DB ₇	DB ₆	DB ₅	DB ₄	DB ₃	DB ₂	DB ₁	DB ₀

FIGURE 6: Two-Byte Read Timing Diagram, ROM Mode

CIRCUIT CHARACTERISTICS

The characteristic curves provide more complete static and dynamic accuracy information necessary for repetitive sampling applications often used in DSP processing. One of the important characteristic curves provided displays integral non-linearity error (INL) versus output code with a typical value of $\pm 1/4$ LSB. Another very important characteristic associated with INL is the transition noise shown in the transition noise cross plot. The ADC-912 offers extremely small, $\pm 1/6$ LSB, transition noise which maintains the system signal-to-noise ratio in DSP processing applications. Code repetition plots show the precision internal comparator of the ADC-912 making the same decision every time for DC input voltages. Code repetition along with no missing codes assures proper performance where the ADC-912 is used in servo-control systems.

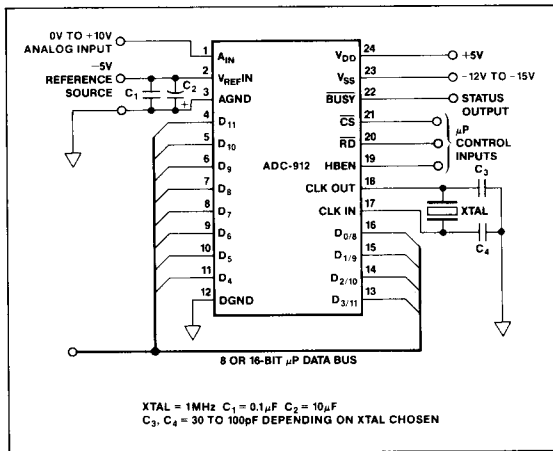


FIGURE 7: Basic Connection Diagram

CONVERTER OPERATION DETAILS

The CS, RD and HBEN digital inputs control the start of conversion. A high-to-low transition on both CS and RD initiate a conversion sequence. The HBEN high-byte-enable input must be low or coincident with the read RD input edge. The start of conversion resets the internal successive approximation register (SAR) and enables the three-state outputs. See Figure 8. The busy line is active low during the conversion process.

During conversion, the SAR sequences the voltage output DAC from the most-significant-bit (MSB) to the least-significant-bit (LSB). The analog input connects to the comparator via a 5kΩ resistor. The DAC which has a 2.5kΩ output resistance connects to the same comparator input. The comparator, performing a zero crossing detection, tests the addition of successively weighted bits from the DAC output versus the analog input signal. The MSB decision occurs after the second negative edge of the CLK IN following conversion initiation. The remaining 11-bit trials occur on the next 11 negative CLK IN edges. Once a conversion cycle is started it cannot be stopped or restarted, without upsetting the remaining bit decisions. Every conversion cycle must have 13 negative CLK IN edges. At the end of conversion the comparator input voltage is zero. The SAR contains the 12-bit data word representing the analog input voltage. The BUSY line returns to logic high, signalling end of conversion. The SAR transfers the new data to the 12-bit latch.

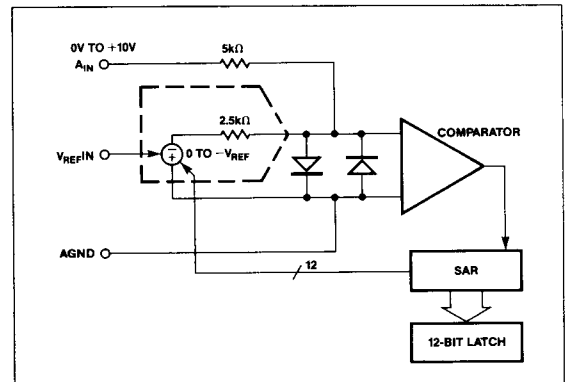
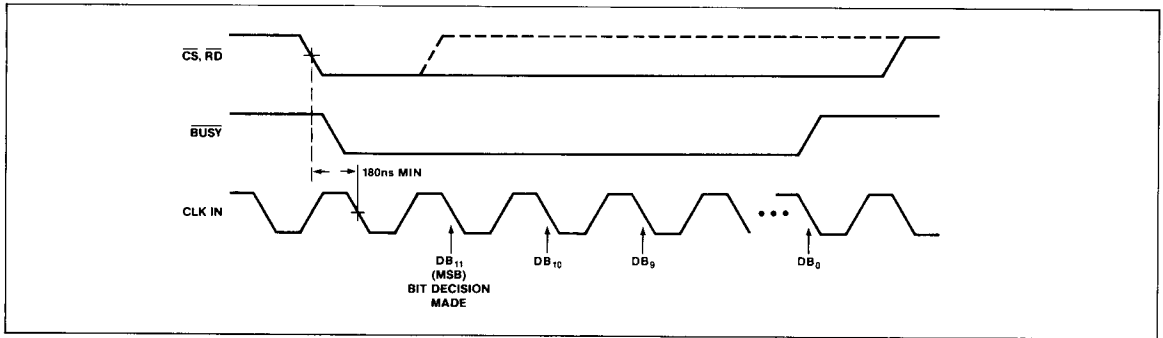


FIGURE 8: Simplified Analog Input Circuitry of ADC-912

SYNCHRONIZING START CONVERSION

Aligning the negative edge of RD with the rising edge of CLK IN provides synchronization of the internal start conversion signal to other system devices for sampling applications.

When the negative edge of RD is aligned with the positive edge of CLK IN, the conversion will take 12.5 microseconds. The minimum setup time between the negative clock edge and the negative edge of RD is 180ns. Without synchronization the conversion time will vary from 12 to 13 clock cycles. See Figure 9.


FIGURE 9: External Clock Input Synchronization

POWER ON INITIALIZATION

During system power-up the ADC-912 comes up in a random state. Once the clock is operating or an external clock is applied, the first valid conversion begins with the application of a high-to-low transition on both CS and RD. The next 13 negative clock edges complete the first conversion producing valid data at the digital outputs. This is important in battery operated systems where power supplies are shut down between measurement times.

DRIVING THE ANALOG INPUT

During conversion, the internal DAC output current modulates the analog input current at the CLK IN frequency of 1MHz. The analog input to the ADC-912 must not change during the conversion process. This requires an external buffer with low output impedance at 1MHz. Suitable devices meeting this requirement include the OP-27, OP-42, and the SMP-11.

INTERNAL CLOCK OSCILLATOR

Figure 10 shows the ADC-912 internal clock circuit. The clock oscillates at the external crystal or ceramic resonator frequency. The 1MHz crystal or ceramic resonator connects between the CLK IN (pin 17) and the CLK OUT (pin 18). Capacitance values (C_1 , C_2) depend on the crystal or ceramic resonator manufacturer recommendations. Typical values range from 30pF to 100pF.

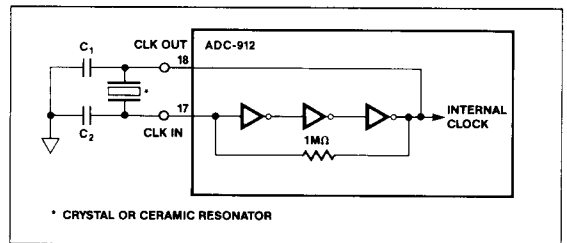
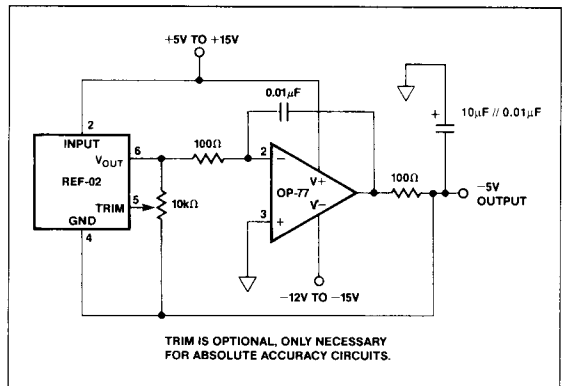
EXTERNAL CLOCK INPUT

A TTL compatible signal connected to CLK IN provides proper converter clock operation. No connection is necessary to the CLK OUT pin. The duty cycle of the external clock input can range from 45% to 55%. Figure 9 shows the important waveforms.

EXTERNAL REFERENCE

A low-output resistance negative-five volt reference is necessary. The external reference should be able to supply 3mA of reference current. A bypass capacitor is necessary on the reference input lead to minimize system noise as the internal DAC switches. A 0.01 μ F capacitor should be located next to the ADC-912. The reference input to the internal DAC is code dependent

requiring anywhere from zero to 3mA. The reference voltage tolerance has a direct influence on A/D converter full-scale voltage, and the maximum input full-scale voltage equals 2 X $-V_{REF}$. The ADC-912 is not designed for ratiometric operation; the range for reference input voltage should be limited to $\pm 5\%$. Figure 11 provides a good negative-five volt reference.


FIGURE 10: ADC-912 Simplified Internal Clock Circuit

FIGURE 11: Negative-Five Volt Reference

UNIPOLAR ANALOG INPUT OPERATION

Figure 12 shows the ideal input/output characteristic for the 0 to 10 volt input range of the ADC-912. The designed output code transitions occur midway between successive integer LSB values (i.e., 0.5 LSB, 1.5 LSBs, 2.5 LSBs, ..., FS - 1.5 LSBs). The output code is natural binary with 1 LSB = FS/4096 = (10/4096)V = 2.44mV. The maximum full-scale input voltage is (10 × 4095/4096)V = 9.9976V, which is 0.5 LSB higher than the last code transition.

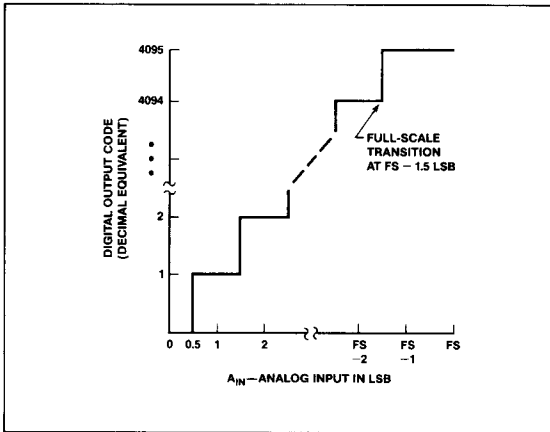


FIGURE 12: Ideal ADC-912 Input/Output Transfer Characteristic

OFFSET AND FULL-SCALE ERROR ADJUSTMENT, UNIPOLAR OPERATION

In applications where absolute accuracy is important then offset and full-scale error can be adjusted to zero. Figure 13 shows the extra components required for full-scale error adjustment. Zero offset is achieved by adjusting the null offset of the op amp driving A_{IN}.

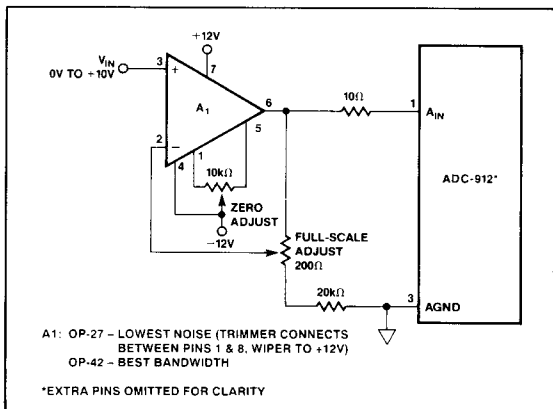


FIGURE 13: Unipolar 0V to +10V Operation

Adjust the zero-scale first by applying 1.22mV (equivalent to 0.5 LSB input) to V_{IN}. Adjust the op amp offset control until the digital output toggles between 0000 0000 0000 and 0000 0000 0001. The next step is adjustment of full scale. Apply 9.9964V (equivalent to FS - 1.5 LSB) to V_{IN} and adjust R1 until the digital output toggles between 1111 1111 1110 and 1111 1111 1111.

BIPOLAR ANALOG INPUT OPERATION

Bipolar analog input operation is achieved with an external amplifier providing an analog offset. Figures 14 and 15 show two circuit topologies that result in different digital-output coding. In Figure 14, offset binary coding is produced when the external amplifier is connected in the noninverting mode. In Figure 15, complementary-offset binary coding is produced when the external amplifier is connected in the inverting mode. Figure 16 shows the ideal transfer characteristics for both the inverting and noninverting configurations given in Figures 14 and 15.

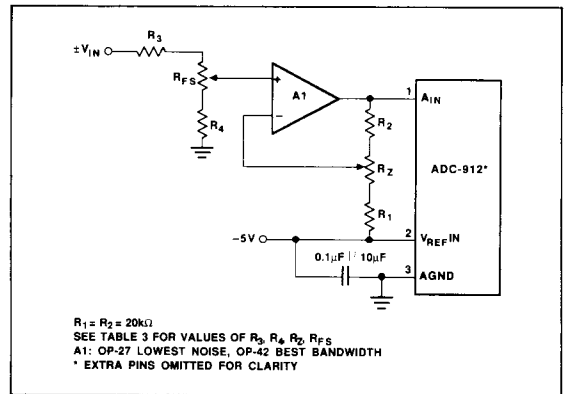


FIGURE 14: Noninverting Bipolar Analog Input Operation

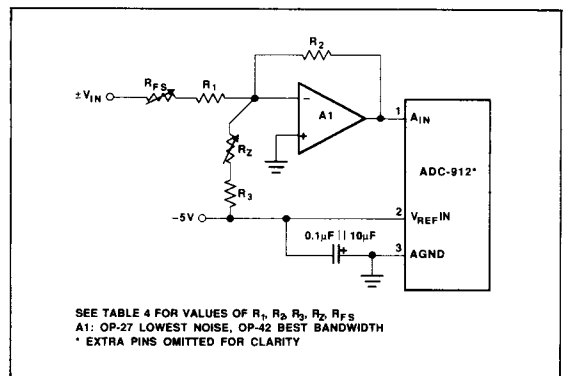


FIGURE 15: Inverting Bipolar Analog Input Operation

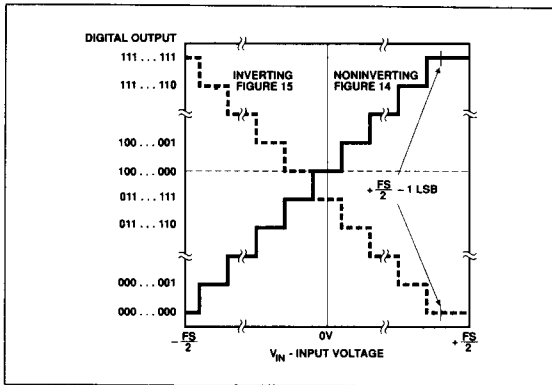


FIGURE 16: Ideal Input/Output Transfer Characteristics for Bipolar Input Circuits

The scaling resistors chosen in bipolar applications should be the same type from the same manufacturer to obtain good performance over temperature. When potentiometers are used for absolute adjustment, 0.1% tolerance resistors should still be used as shown in Figures 14 and 15 to minimize temperature coefficient errors.

Calibration of the bipolar analog input circuits (Figures 14 and 15) should begin with zero adjustment first. Apply a +1/2 LSB analog input to A_{IN}, (see Tables 3 and 4) and adjust R_Z until the successive digital output codes flicker between the following codes:

- For noninverting, Figure 14 1000 0000 0000
- 1000 0000 0001
- For inverting, Figure 15 0111 1111 1111
- 0111 1111 1110

Next, adjust full scale by applying a FS-3/2 LSB analog input to A_{IN}, (see Tables 3 and 4) and adjust R_{FS} until the successive digital output codes flicker between the following codes:

- For noninverting, Figure 14 1111 1111 1110
- 1111 1111 1111
- For inverting, Figure 15 0000 0000 0001
- 0000 0000 0000

TABLE 3: Resistor and Potentiometer Values Required for Figure 14

V _{IN} RANGE (VOLTS)	R ₃ (kΩ)	R ₄ (kΩ)	R _Z (kΩ)	R _{FS} (kΩ)	1/2 LSB (mV)	FS/2-3/2 LSB (VOLTS)
±2.5	0	40.2	0.5	0.5	0.61	2.49817
±5.0	20.0	19.8	0.5	1.0	1.22	4.99634
±10.0	29.8	10.0	0.5	0.5	2.44	9.99268

TABLE 4: Resistor and Potentiometer Values Required for Figure 15

V _{IN} RANGE (VOLTS)	R ₁ (kΩ)	R ₂ (kΩ)	R ₃ (kΩ)	R _Z (kΩ)	R _{FS} (kΩ)	1/2 LSB (mV)	FS/2-3/2 LSB (VOLTS)
±2.5	20.0	41.2	40.2	2	1	0.61	2.49817
±5.0	20.0	20.5	20.0	1	1	1.22	4.99634
±10.0	20.0	10.5	10.2	0.5	1	2.44	9.99268

MICROPROCESSOR INTERFACING

The ADC-912 has self-contained logic for both 8-bit and 16-bit data bus interfacing. The output data can be formatted into either a 12-bit parallel word for a 16-bit data bus or an 8-bit data word pair for an 8-bit data bus. Data is always right justified, i.e., LSB is the most right-hand bit in a 16-bit word. For a two-byte read, only data outputs D₇...D_{0/8} are used. Byte selection is governed by the HBEN input which controls an internal digital

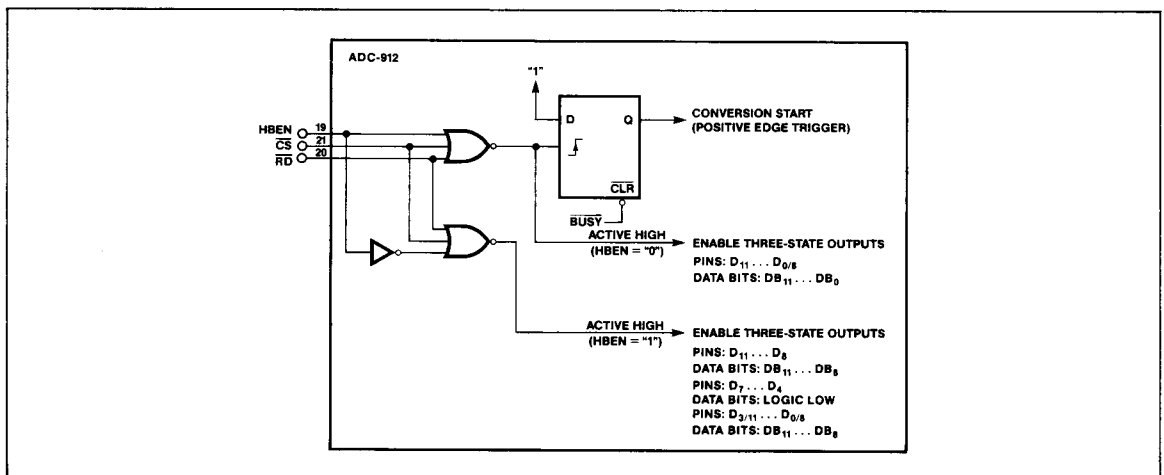


FIGURE 17: Internal Logic for Control Inputs CS, RD, and HBEN

multiplexer. This multiplexes the 12-bits of conversion data onto the lower $D_7 \dots D_{0/8}$ outputs (4 MSBs or 8 LSBs) where it can be read in two read cycles. The 4 MSBs always appear on $D_{11} \dots D_8$ whenever the three-state output drivers are turned on. See Figure 17.

Two A/D conversion modes of operation are available for both data bus sizes: the ROM mode and the Slow-Memory mode.

In the ROM mode each READ instruction obtains new, valid data assuming the minimum timing requirements are satisfied. However, since the data output from a current READ instruction was generated from a conversion initiated by a previous READ operation, the current data may be out-of-date. To be sure of obtaining up-to-date data, READ instructions may be coded in pairs (with some NOPs between them); use only the data from the second READ in each pair. The first READ starts the conversion, the second READ gets the results.

The Slow-Memory mode is the simplest mode. It is the method of choice where compact coding is essential, or where software bugs are a hazard. In this mode, a single READ instruction will initiate a data conversion, interrupt the microprocessor until completion (WAIT states are introduced), then read the results. If the system throughput tolerates WAIT states, and the hardware is correct, then the Slow-Memory mode is virtually immune to subsequent software modifications. Placing the microprocessor in the WAIT state has an additional advantage of quieting the digital system to reduce noise pickup in the analog conversion circuitry. The 12-bit parallel Slow-Memory mode provides the fastest analog sampling rate combined with digital data transfer rate for sampled-data systems.

PARALLEL READ, SLOW-MEMORY MODE (HBEN = LOW)

Figure 3 shows the timing diagram and data bus status for Parallel Read, Slow-Memory Mode. CS and RD going low triggers a conversion and the ADC-912 acknowledges by taking BUSY low. Data from the previous conversion appears on the three-state data outputs. BUSY returns high at the end of conversion, when the output latches have been updated, and the conversion result is placed on data outputs $D_{11} \dots D_{0/8}$.

TWO-BYTE READ, SLOW-MEMORY MODE

For a two-byte read only the 8 data outputs $D_7 \dots D_{0/8}$ are used. Conversion start procedure and data output status for the first read operation is identical to Parallel Read, Slow-Memory Mode. See Figure 4, Timing Diagram and Data Bus Status. At the end of conversion, the low data byte ($DB_7 \dots DB_0$) is read from the A/D converter. A second READ operation with HBEN high, places the high byte on data outputs $D_{3/11} \dots D_{0/8}$ and disables conversion start. Note the 4 MSBs appear on data outputs $D_{11} \dots D_8$ during these two READ operations.

PARALLEL READ, ROM MODE (HBEN = LOW)

A conversion is started with a READ operation. The 12 bits of data from the previous conversion are available on data outputs $D_{11} \dots D_{0/8}$ (see Figure 5). This data may be disregarded if not required. A second READ operation reads the new data ($DB_{11} \dots DB_0$) and starts another conversion. A delay at least as long as the ADC-912 conversion time must be allowed between READ operations. If a READ takes place prior to the end of 13 CLKs of the ADC conversion, the remaining bits not yet tested will be invalid.

TWO-BYTE READ, ROM MODE

For a two-byte read only the data outputs $D_7 \dots D_{0/8}$ are used. Conversion is started in the same way with a READ operation and the data output status is the same as the Parallel Read, ROM Mode. See Figure 6, Two-Byte Read Timing Diagram. Two more READ operations are required to obtain the new conversion result. A delay equal to the ADC-912 conversion time must be allowed between conversion start and the second data READ operation. The second READ operation, with HBEN high, disables conversion start and places the high byte (4 MSBs) on data outputs $D_{3/11} \dots D_{0/8}$. A third READ operation accesses the low data byte ($DB_7 \dots DB_0$) and starts another conversion. The 4 MSBs appear on data outputs $D_{11} \dots D_8$ during all three read operations above.

CIRCUIT LAYOUT GUIDELINES

As with any high speed A/D converters good circuit layout practice is essential. Wire-wrap boards are not recommended due to stray pickup of the high frequency digital noise. A PC board offers the best results. Digital and analog grounds should be separated even if they are ground planes instead of ground traces. Don't lay digital traces adjacent to high impedance analog traces. Avoid digital layouts that radiate high frequency clock signals, i.e., don't lay out digital signal lines and ground returns in the shape of a loop antenna. Shield the analog input if it comes from a different PC board source. Set up a single point ground at AGND (pin 3) of the ADC-912. Tie all other analog grounds to this point. Also tie the logic power supply ground, but no other digital grounds to this point (see Figure 18). Low impedance analog and digital power supply common returns are essential to low noise operation of the ADC. Their trace widths should be as wide as possible. Good power supply bypass capacitors located near the ADC package insure quiet operation. Place a $10\mu\text{F}$ capacitor in parallel with a $0.01\mu\text{F}$ ceramic capacitor across V_{DD} to ground and V_{SS} to ground (near pin 3).

In applications where the ADC-912 outputs and control signals are connected to a continuously active microprocessor bus, it is possible to get LSB level errors in conversion results. These errors are due to a feedthrough from the microprocessor to the internal comparator. The problem can be minimized by forcing the microprocessor into a WAIT state during conversion

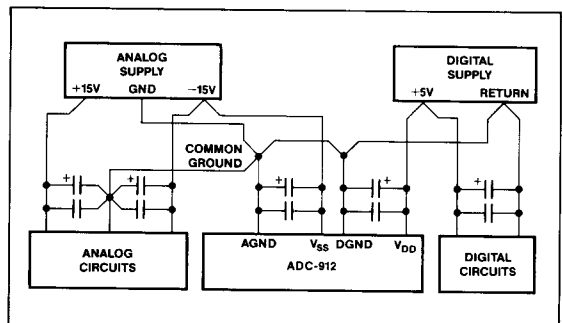


FIGURE 18: Power Supply Grounding

(see Slow-Memory Mode microprocessor interfacing). An alternate method is isolation of the data bus with three-state buffers, such as the 74HC541.

INTERFACING TO THE TMS32010 DSP PROCESSOR

Figure 19 shows an ADC-912 to TMS32010 interface. The ADC-912 is operating in the ROM Mode. The interface is designed for a maximum TMS32010 clock frequency of 18.6MHz but will typically work over the full 20MHz TMS32010 clock frequency range.

The ADC-912 is mapped at a user-selected port address (PA). The following I/O instruction starts a conversion and reads the previous conversion into the data memory.

IN DATA, PA PA = Port Address
DATA = Data Memory Location

When conversion is complete, a second I/O instruction reads the new data into the data memory and starts another conversion. Sufficient A/D conversion time must be allowed between I/O instructions. The very first data read after system power-up should be discarded.

USING WAIT STATES

The TMS32020 DSP processor has the added capability of WAIT states. This feature simplifies the hardware required for slow memory devices by extending the microprocessor bus access time. Figure 20 shows an ADC-912 to TMS32020

interface using one WAIT state to guarantee data interface at the full 20MHz clock frequency. This WAIT state extends the bus access time by 200ns. In this circuit the ADC-912 operates in the ROM mode where each input instruction (IN DATA, PA) takes the previous conversion result and stores it in memory. The next input instruction must be delayed for the length of the A/D conversion time so that a new conversion result can be read.

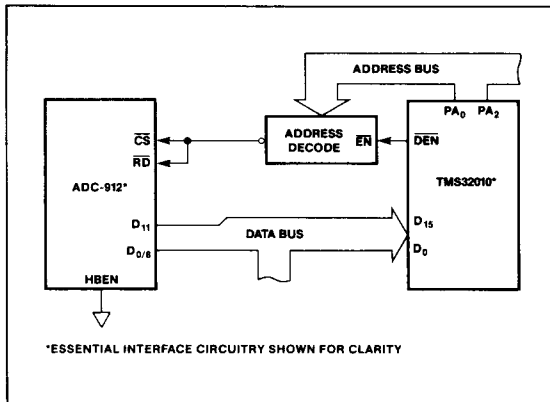


FIGURE 19: ADC-912 to TMS32010 DSP Processor Interface

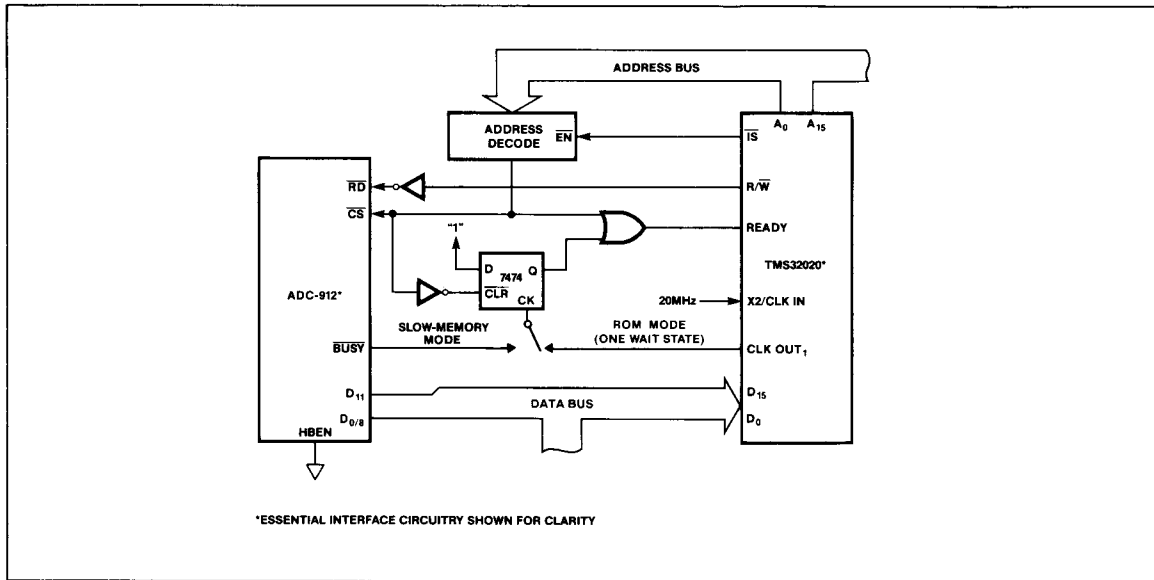


FIGURE 20: ADC-912 to TMS32020 Interface Using WAIT States

SLOW-MEMORY MODE OPERATION USING WAIT STATES

The WAIT state feature of the TMS32020 can also be used to operate the ADC-912 in the Slow-Memory mode. This is accomplished by driving the clock input of the 7474 flip-flop in Figure 20, from the BUSY output of the ADC-912, instead of the CLK OUT1 of the TMS32020. Once a conversion has started the READY input of the TMS32020 is not released until the ADC-912 completes its 12-bit A/D conversion. This stops the

TMS32020 during the conversion process reducing microprocessor system noise generation. Another advantage for the system software is the single instruction IN MEM, PA used to start, process, and read the results of the A/D conversion. This makes the software code more transportable between systems operating at different clock speeds. The disadvantage is some loss in instruction processing time.

BURN-IN CIRCUIT

